

NOT RECOMMENDED FOR NEW DESIGN **USE DMP3018SSS**



DMG4407SSS

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C		
001/	11mΩ @ V _{GS} = -20V	-9.9A		
-30V	17mΩ @ V _{GS} = -6V	-8.2A		

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

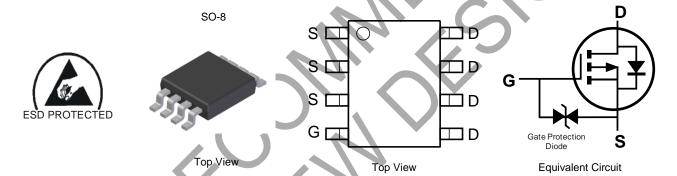
- Backlighting
- **Power Management Functions**
- DC-DC Converters

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.075 grams (Approximate)

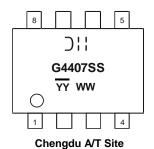


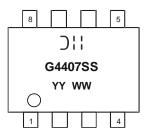
Ordering Information (Note 4)

Part Number	Case	Packaging
DMG4407SSS-13	SO-8	2500/Tape & Reel

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain < 900ppm bromine, < 900ppm chlorine (< 1500ppm total Br + CI) and
 - For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Shanghai A/T Site

⊃¦¦ = Manufacturer's Marking G4407SS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 18 = 2018) WW = Week (01 to 53)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test site) YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			V_{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±25	V
Continuous Dunin Courset (Alata C) V 200V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-9.9 -7.9	А
Continuous Drain Current (Note 6) V _{GS} = -20V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-12.5 -10.0	Α
Continuous Drain Current (Note 6) V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	I _D	-8.2 -6.5	Α
Continuous Drain Current (Note 6) V _{GS} = -6V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-11.0 -8.7	Α
Maximum Continuous Body Diode Forward Current (Note 6)			Is	-3.0	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-80	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.45	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Paus	88	°C/W
Thermal Resistance, Junction to Ambient (Note 3)	t<10s	Reja	50	°C/W
Total Power Dissipation (Note 6)		P_{D}	1.82	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Pau	70	°C/W
Thermal Resistance, Junction to Ambient (Note o)	t<10s	R ₀ JA	41	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	7.6	°C/W
Operating and Storage Temperature Range		TJ, T _{STG}	-50 to +155	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	1	_	-1	μΑ	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±10	μΑ	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(TH)}$	-1.7	_	-3.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
		_	9	11		$V_{GS} = -20V, I_D = -12A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	10	13	mΩ	$V_{GS} = -10V, I_D = -10A$	
		_	12.7	17		$V_{GS} = -6V, I_D = -10A$	
Forward Transfer Admittance	Y _{fs}	_	21	_	S	$V_{DS} = -5V, I_{D} = -10A$	
Diode Forward Voltage		_	-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}		2246	_	pF	15)/)/ 0)/	
Output Capacitance	Coss	1	352	_	pF	$V_{DS} = -15V, V_{GS} = 0V,$ - f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}		294	_	pF	1 – 1.01/11/12	
Gate Resistance	R _g	_	5.1	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	20.5	_	nC		
Total Gate Charge (V _{GS} = -10V)		_	41	_	nC	$V_{GS} = -10V, V_{DS} = -15V,$	
Gate-Source Charge	Q _{gs}	_	7.6	_	nC	I _D = -12A	
Gate-Drain Charge	Q_{gd}	_	8.0	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	11.3	_	ns		
Turn-On Rise Time			15.4	_	ns	$V_{DD} = -15V, V_{GS} = -10V,$	
Turn-Off Delay Time		_	38.0	_	ns	$R_L = 1.25\Omega$, $R_G = 3\Omega$	
Turn-Off Fall Time		_	22.0	_	ns	7	

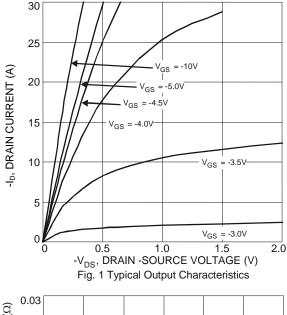
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect. Notes:

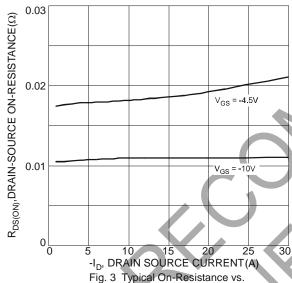
8. Guaranteed by design. Not subject to product testing.

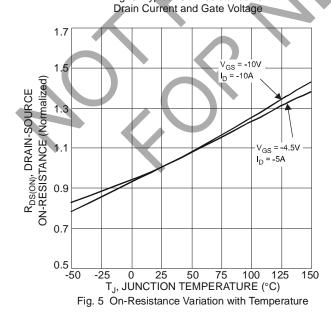


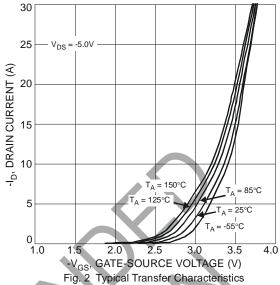
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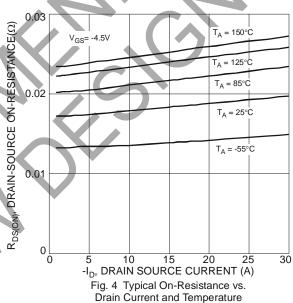
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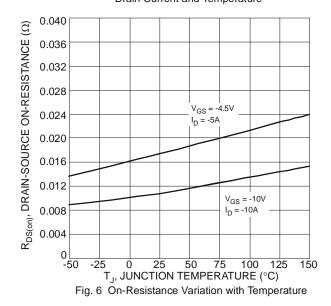














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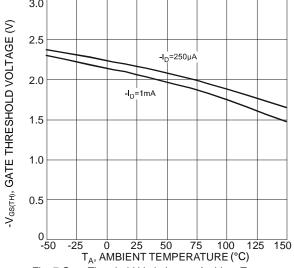
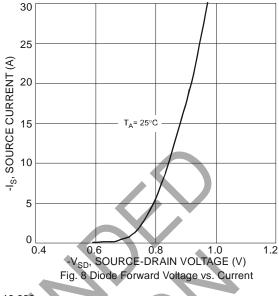
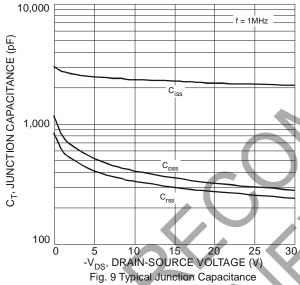
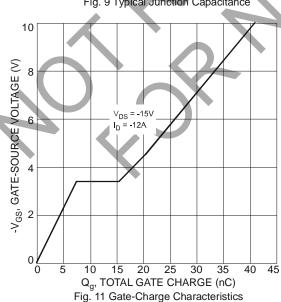


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







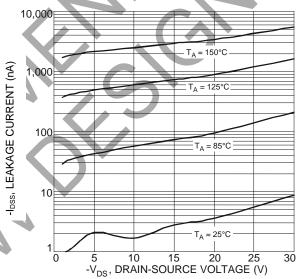
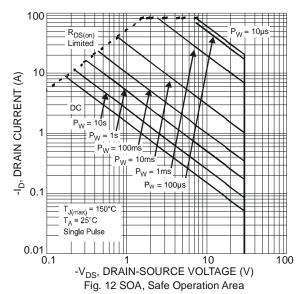
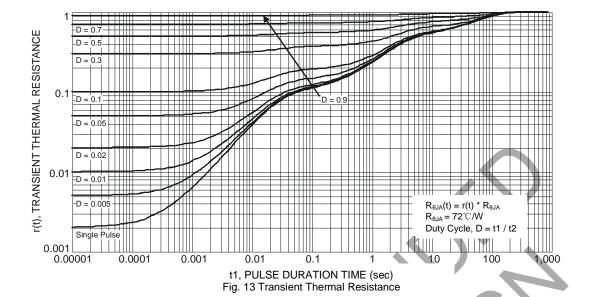


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage





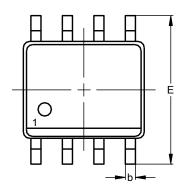


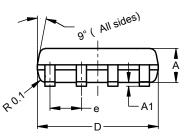


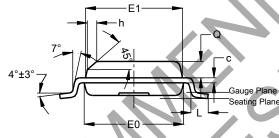
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8





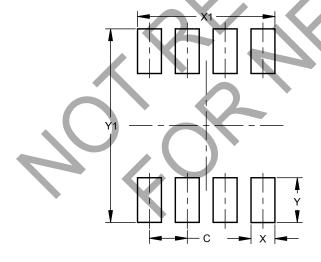


SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h	J	1	0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)
C	1.27
X	0.802
X1	4.612
Y	1.505
Y1	6.50



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